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## **P-Channel Power MOSFET**

-20V, -6.5A, 26mΩ

#### **FEATURES**

- Fast switching
- Suitable for -1.8V Gate Drive Applications
- Pb-free plating
- RoHS compliant
- Halogen-free mold compound

KEY PERFORMANCE PARAMETERS				
PARAMETER		VALUE	UNIT	
$V_{DS}$		-20	V	
Ι <sub>D</sub>		-6.5	Α	
	V <sub>GS</sub> = -4.5V	26		
R <sub>DS(on)</sub> (max)	$V_{GS} = -2.5V$	32	mΩ	
	V <sub>GS</sub> = -1.8V	40		
$\mathbf{Q}_{g}$		19.5	nC	

#### **APPLICATION**

- Battery Pack
- Portable Devices

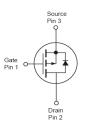












Notes: Moisture sensitivity level: level 3. Per J-STD-020

ABSOLUTE MAXIMUM RATINGS (T <sub>A</sub> = 25°C unless otherwise noted)					
PARAMETER		SYMBOL	LIMIT	UNIT	
Drain-Source Voltage		$V_{DS}$	-20	V	
Gate-Source Voltage		$V_{GS}$	±10	V	
Continuous Drain Current	$T_C = 25^{\circ}C$		-6.5		
	T <sub>C</sub> = 100°C	I <sub>D</sub>	-4.1	_ A	
Pulsed Drain Current (Note 1)		I <sub>DM</sub>	-26	Α	
Total Power Dissipation	$T_C = 25^{\circ}C$	P <sub>DTOT</sub>	1.56	W	
Operating Junction Temperature		TJ	150	ōС	
Operating Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>STG</sub>	- 55 to +150	°C	

THERMAL PERFORMANCE					
PARAMETER	SYMBOL	LIMIT	UNIT		
Junction to Ambient Thermal Resistance	$R_{\Theta JA}$	80	°C/W		

**Notes:**  $R_{\Theta JA}$  is the sum of the junction-to-case and case-to-ambient thermal resistances.  $R_{\Theta JA}$  is guaranteed by design while  $R_{\Theta CA}$  is determined by the user's board design.  $R_{\Theta JA}$  is shown for single device operation on FR-4 PCB in still air.



<b>ELECTRICAL SPECIFICATIONS</b> (T <sub>A</sub> = 25°C unless otherwise noted)						
PARAMETER	CONDITIONS	SYMBOL	MIN	TYP	MAX	UNIT
Static (Note 2)						_
Drain-Source Breakdown Voltage	$V_{GS} = 0V, I_D = -250\mu A$	BV <sub>DSS</sub>	-20			V
Gate Threshold Voltage	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$	$V_{GS(TH)}$	-0.3	-0.6	-1.0	V
Gate Body Leakage	$V_{GS} = \pm 10V$ , $V_{DS} = 0V$	I <sub>GSS</sub>			±100	nA
Zero Gate Voltage Drain Current	$V_{DS} = -20V, V_{GS} = 0V$				-1	μΑ
	$V_{DS} = -16V, T_J = 125^{\circ}C$	I <sub>DSS</sub>			-10	
	$V_{GS} = -4.5V, I_D = -5A$			21	26	mΩ
Drain-Source On-State Resistance	$V_{GS} = -2.5V, I_D = -4A$	R <sub>DS(on)</sub>		26	32	
	$V_{GS} = -1.8V, I_D = -3A$			32	40	
Forward Transconductance	$V_{DS} = -10V, I_{S} = -5A$	g <sub>fs</sub>		15		S
Dynamic (Note 3)						
Total Gate Charge		$Q_g$		19.5		
Gate-Source Charge	$V_{DS} = -10V, I_{D} = -5A,$	$Q_gs$		2		nC
Gate-Drain Charge	V <sub>GS</sub> =- 4.5V	$Q_{gd}$		3.6		
Input Capacitance		C <sub>iss</sub>		1670		
Output Capacitance	$V_{DS} = -15V, V_{GS} = 0V,$	C <sub>oss</sub>		220		pF
Reverse Transfer Capacitance	F = 1.0MHz	C <sub>rss</sub>		120		
Switching						
Turn-On Delay Time		t <sub>d(on)</sub>		10.4		
Turn-On Rise Time	$V_{DD} = -10V, I_{D} = -1A,$ $V_{GS} = -4.5V, R_{GEN}$ $= 25\Omega$	t <sub>r</sub>		37.5		
Turn-Off Delay Time		t <sub>d(off)</sub>		89.1		ns
Turn-Off Fall Time	- =2011	t <sub>f</sub>		24.6		
Source-Drain Diode						
Forward Voltage	$V_{GS} = 0V, I_{S} = -1A$	$V_{SD}$			-1	٧
Continuous Forward Current	Integral reverse diode	I <sub>S</sub>			-6.5	Α
Pulse Forward Current	in the MOSFET	I <sub>SM</sub>			-26	Α

#### Notes:

- 1. Pulse width limited by safe operating area
- 2. Pulse test: PW  $\leq$  300 $\mu$ s, duty cycle  $\leq$  2%
- Switching time is essentially independent of operating temperature.



Taiwan Semiconductor

#### **ORDERING INFORMATION**

PART NO.	PACKAGE	PACKING
TSM260P02CX RFG	SOT-23	3,000pcs / 7" Reel
TSM260P02CX6 RFG	SOT-26	3,000pcs / 7" Reel

#### Note:

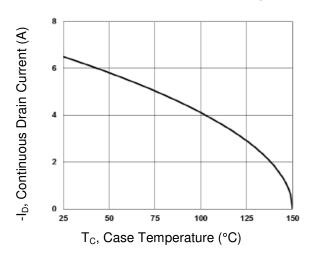
- 1. Compliant to RoHS Directive 2011/65/EU and in accordance to WEEE 2002/96/EC
- 2. Halogen-free according to IEC 61249-2-21 definition



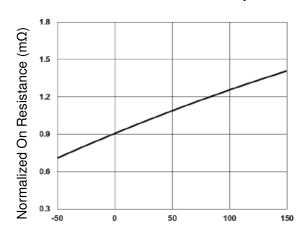
#### **CHARACTERISTICS CURVES**

(T<sub>C</sub> = 25°C unless otherwise noted)

#### Continuous Drain Current vs. Tc

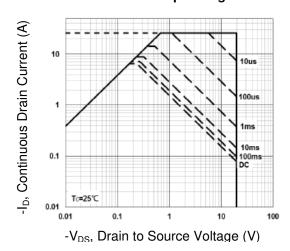


#### **On-Resistance vs. Junction Temperature**

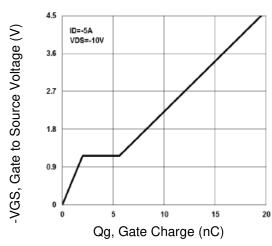


T<sub>J</sub>, Junction Temperature (°C)

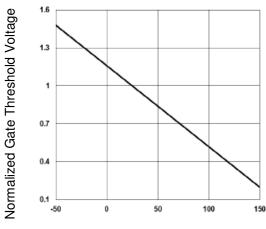
#### **Maximum Safe Operating Area**



#### Gate Charge

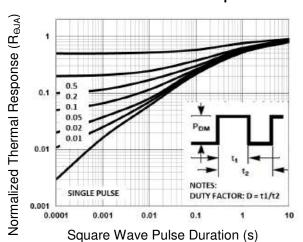


#### Threshold Voltage vs. Junction Temperature



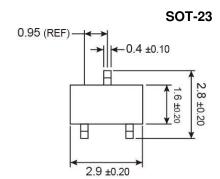
T<sub>J</sub>, Junction Temperature (°C)

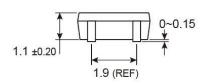
#### **Normalized Thermal Transient Impedance Curve**

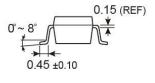




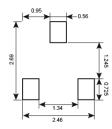
## PACKAGE OUTLINE DIMENSIONS (Unit: Millimeters)







### SUGGESTED PAD LAYOUT (Unit: Millimeters)



#### **MARKING DIAGRAM**



**26** = Device Code

Y = Year Code

**M** = Month Code for Halogen Free Product

 $\mathbf{O}$  =Jan  $\mathbf{P}$  =Feb  $\mathbf{Q}$  =Mar  $\mathbf{R}$  =Apr

 $S = May \quad T = Jun \quad U = Jul \quad V = Aug$ 

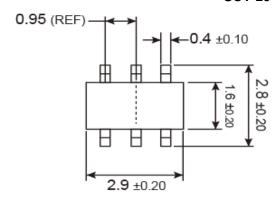
 $W = Sep \quad X = Oct \quad Y = Nov \quad Z = Dec$ 

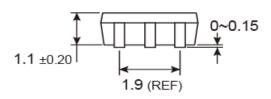
L = Lot Code

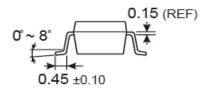


## PACKAGE OUTLINE DIMENSIONS (Unit: Millimeters)

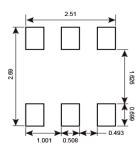
**SOT-26** 







### SUGGESTED PAD LAYOUT (Unit: Millimeters)



### **MARKING DIAGRAM**



26 = Device Code

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**L** = Lot Code  $(1 \sim 9, A \sim Z)$ 



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